



74LVC2G17

DUAL SCHMITT TRIGGER BUFFERS

DFN1010

Description

The 74LVC2G17 is a dual Schmitt trigger inverter gate with standard push-pull outputs. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using $I_{\rm OFF}$. The $I_{\rm OFF}$ circuitry disables the output preventing damaging current backflow when the device is powered down.

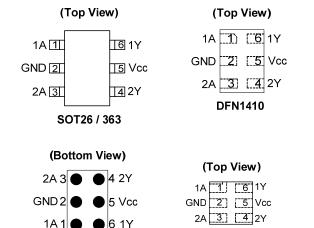
The gate performs the positive Boolean function:

Y = A

Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- ±24mA Output Drive at 3.0V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- DFN1409 package designed as a direct replacement for chip scale packaging.
- Range of Package Options SOT26, SOT353, DFN1010, DFN1409 and DFN1410
- Leadless packages per JESD30E
 - DFN1410 denoted as X2-DFN1410-6
 - DFN1409 denoted as X2-DFN1409-6
 - DFN1010 denoted as X2-DFN1010-6
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:

DFN1409

Chip Scale

Alternative

- PCs, networking, notebooks, netbooks, tablets
- Computer peripherals, hard drives, CD/DVD ROM
- TV, DVD, DVR, set top box
- Cell Phones, Personal Navigation / GPS
- MP3 players ,Cameras, Video Recorders

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and < 1000 ppm antimony compounds.

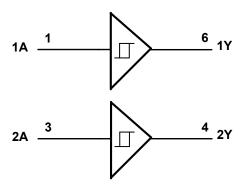
Click here for ordering information, located at the end of datasheet



Pin Descriptions

Pin Name	Pin NO.	Function
1A	1	Data Input
GND	2	Ground
2A	3	Data Input
2Y	4	Data Output
V _{CC}	5	Supply Voltage
1Y	6	Data Output

Logic Diagram



Function Table

Inputs	Output
Α	Υ
Н	Н
L	L

Absolute Maximum Ratings (Note 4) (@TA = +25°C, unless otherwise specified.)

Symbol	Function	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +6.5	V
VI	Input Voltage Range	-0.5 to +6.5	V
Vo	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to +6.5	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
lıĸ	Input Clamp Current V _I < 0	-50	mA
I _{OK}	Output Clamp Current V _O < 0	-50	mA
Io	Continuous Output Current	-50	mA
_	Continuous Current Through V _{DD} or GND	±100	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Note:

^{4.} Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol		Parameter	Min	Max	Unit	
	Operating Voltage	Operating	1.65	5.5	V	
Vcc	Operating Voltage	Data retention only	1.5	_	V	
V_{I}	Input Voltage		0	5.5	V	
Vo	Output Voltage		0	V _{CC}	V	
		V _{CC} = 1.65V	_	-4		
		V _{CC} = 2.3V	_	-8		
I_{OH}	I _{OH} High-Level Output Current	High-Level Output Current	V = 2V	_	-16	mA
		V _{CC} = 3V	_	-24		
		V _{CC} = 4.5V	_	-32		
		V _{CC} = 1.65V	_	4		
		V _{CC} = 2.3V	_	8		
I_{OL}	Low-Level Output Current	V = 2V	_	16	mA	
		V _{CC} = 3V	_	24		
		V _{CC} = 4.5V	_	32		
		V _{CC} = 1.8V ± 0.15V, 2.5V ± 0.2V	_	20		
Δt/ΔV	Input transition rise or fall rate	$V_{CC} = 3.3V \pm 0.3V$	_	10	ns/V	
		$V_{CC} = 5V \pm 0.5V$	_	5	1	
TA	Operating free-air temperature	_	-40	+125	°C	

Note:

5. Unused inputs should be held at V_{CC} or Ground.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Cumbal	Dovemeter	Test Conditions	V	-40°C to	+85°C	-40°C to	+125°C	l lm!4
Symbol	Parameter	Test Conditions	V _{CC}	Min	Max	Min	Max	Unit
			1.8V	0.70	1.50	0.70	1.70	
			2.3V	1.00	1.80	1.00	2.00	
V_{T+}	Positive-going input	_	3V	1.30	2.20	1.30	2.40	V
	threshold voltage		4.5V	1.90	3.10	1.90	3.30	
			5.5V	2.20	3.60	2.20	3.80	
			1.65V	0.25	0.90	0.39	1.10	
			2.3V	0.40	1.15	0.25	0.87	
V_{T-}	Negative-going input	_	3V	0.60	1.50	0.40	1.35	V
	threshold voltage		4.5V	1.00	2.00	0.60	1.70	
			5.5V	1.20	2.30	1.00	2.50	
			1.8V	0.15	1.00	0.37	1.20	
			2.3V	0.25	1.10	0.15	1.30	
ΔV_T	Hysteresis (V _{T+} - V _{T-)}	_	3V	0.40	1.20	0.40	1.40	μA
			4.5V	0.60	1.50	0.60	1.70	
				5.5V	0.70	1.70	0.70	1.90
		I _{OH} = -100μA	1.65V to 4.5V	V _{CC} - 0.1	_	V _{CC} - 0.1	_	
		$I_{OH} = -4mA$	1.65V	1.2	_	0.95	_	
\ /	Liberta Laurel Outrout Vallana	$I_{OH} = -8mA$	2.3V	1.9	_	1.7	_] ,
V_{OH}	High-Level Output Voltage	I _{OH} = -16mA	2) /	2.4	1	1.9	_	V
		$I_{OH} = -24mA$	3V	2.3	1	2.0	_	
		$I_{OH} = -32mA$	4.5V	3.8	1	3.4	_	
		I _{OL} = 100μA	1.65V to 4.5V	_	0.1	_	0.10	
		I _{OL} = 4mA	1.65V	_	0.45	_	0.70	
V	Lavelavel Output Valtage	I _{OL} = 8mA	2.3V	_	0.3	_	0.45	
V_{OL}	Low-Level Output Voltage	I _{OL} = 16mA	2) /	_	0.4	_	0.60	V
		I _{OL} = 24mA	3V	_	0.55	_	0.80	
		$I_{OL} = 32mA$	4.5V	_	0.55	_	0.80	
Ι _Ι	Input Current	V _I = 5.5V or GND	0 to 5.5V	_	± 5	_	± 20	μA
I _{OFF}	Power Down Leakage Current	V_1 or $V_0 = 5.5V$	0	_	± 10	_	± 20	μA
Icc	Supply Current	$V_1 = 5.5V$ or GND, $I_0 = 0$	1.65V to 5.5V	_	10	_	40	μA



Package Characteristics ((@T_A = +25°C, V_{CC} = 3.3V, unless otherwise specified.)

Symbol	Parameter	Package	Conditions	Min	Тур	Max	Unit
Cı	Input Capacitance	Typical of all packages	$Vcc = 3.3V$ $V_{I} = V_{CC} - or GND$	_	3.5	_	pF
		SOT26		_	204	_	
		SOT363		_	371	_	
θ_{JA}	Thermal Resistance Junction-to-	X2-DFN1410-6	(Note 6)	_	430	_	°C/W
	Ambient	X2-DFN1409-6		_	450	_	
		X2-DFN1010-6		_	510	_	
		SOT26		_	52	_	
		SOT363		_	143	_	
θ_{JC}	Thermal Resistance Junction-to- Case	X2-DFN1410-6	(Note 6)	_	190	_	°C/W
		X2-DFN1409-6		_	225	_	
		X2-DFN1010-6		_	250	_	

Note:

Switching Characteristics

 $T_A = -40$ °C to +85°C, $C_L = 30$ or 50pF (see Figure 1)

Parameter	From	TO (OUTPUT)		: 1.8V .15V		: 2.5V).2V		: 3.3V .3V		= 5V).5V	Unit
	(Input)	(001701)	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	Α	Υ	0.5	10.5	0.5	6.5	0.5	5.7	0.5	4.3	ns

 T_A = -40°C to +125°C, C_L = 30 or 50pF (see Figure 1)

Parameter	From (Input)	TO (OUTPUT)		= 1.8V .15V		= 2.5V).2V	V _{CC} = ± 0	: 3.3V).3V		= 5V).5V	Unit
	(iliput)	(001701)	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	Α	Υ	0.5	13.1	0.5	8.5	0.5	7.1	0.5	5.4	ns

Operating Characteristics

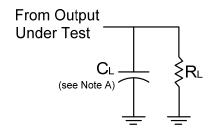
 $T_A = +25^{\circ}C$

	Parameter	Test	V _{CC} = 1.8V	V _{CC} = 2.5V	V _{CC} = 3.3V	V _{CC} = 5V	Unit
	- urumotor	Conditions	Тур	Тур	Тур	Тур	Onit
$C_{\sf pd}$	Power dissipation capacitance	f = 10MHz	17	19	20	21	pF

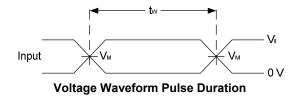
^{6.} Test condition for SOT26, SOT363, X2-DFN1410-6, X2-DFN1409-6 and X2-DFN1010 -6: Device mounted on FR-4 substrate PC board, 2oz copper with minimum recommended pad layout.

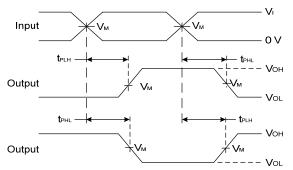


Parameter Measurement Information



V	Inp	outs	V	_	Б	
V _{CC}	VI	t _r /t _f	V _M	CL	R_L	
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	30pF	1kΩ	
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	30pF	500Ω	
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω	
5V±0.5V	Vcc	≤2.5ns	V _{CC} /2	50pF	500Ω	





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

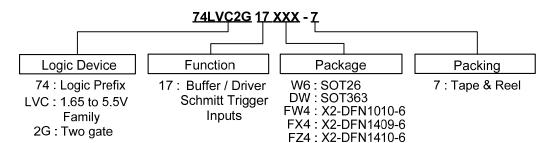
Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{PD}. \label{eq:decomposition}$



Ordering Information

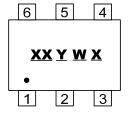


Device	Backaga Codo	Packaging	7" Tape	and Reel
Device	Package Code	(Note 7)	Quantity	Part Number Suffix
74LVC2G17W6-7	W6	SOT26	3000/Tape & Reel	-7
74LVC2G17DW-7	DW	SOT363	3000/Tape & Reel	-7
74LVC2G17FW4-7	FW4	X2-DFN1010-6	5000/Tape & Reel	-7
74LVC2G17FX4-7	FX4	X2-DFN1409-6	5000/Tape & Reel	-7
74LVC2G17FZ4-7	FZ4	X2-DFN1410-6	5000/Tape & Reel	-7

7. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf Note:

Marking Information

(1) SOT26, SOT363



XX: Identification code

Y: Year 0~9

W: Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents

52 and 53 week X: A~Z: Internal Code

Part Number	Package	Identification Code
74LVC2G17W6	SOT26	Z 6
74LVC2G17DW	SOT363	Z 6

(2) X2-DFN1010-6, X2-DFN1409-6, X2-DFN1410-6

(Top View)

XX $\frac{XX}{Y}$: Identification Code $\frac{X}{Y}$: Year: 0~9

<u>W</u>: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents

52 and 53 week X: A~Z: Internal code

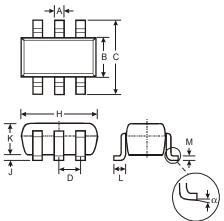
Part Number	Package	Identification Code
74LVC2G17FW4	X2-DFN1010-6	Z 6
74LVC2G17FX4	X2-DFN1409-6	X6
74LVC2G17FZ4	X2-DFN1410-6	Z6



Package Outline Dimensions (All dimensions in mm.)

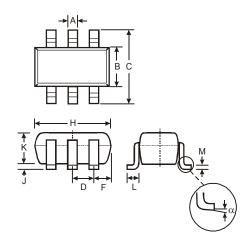
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(1) Package Type: SOT26



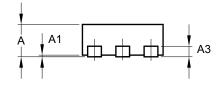
	SOT26			
Dim	Min	Max	Тур	
Α	0.35	0.50	0.38	
В	1.50	1.70	1.60	
С	2.70	3.00	2.80	
D		_	0.95	
Н	2.90	3.10	3.00	
J	0.013	0.10	0.05	
K	1.00	1.30	1.10	
L	0.35	0.55	0.40	
M	0.10	0.20	0.15	
α	0°	8°	_	
All Dimensions in mm				

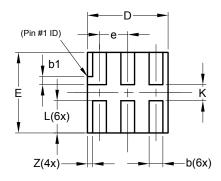
(2) Package Type: SOT363



SOT363			
Dim	Min	Max	Тур
Α	0.10	0.30	0.25
В	1.15	1.35	1.30
С	2.00	2.20	2.10
D		0.65 Ty	р
F	0.40	0.45	0.425
Н	1.80	2.20	2.15
J	0	0.10	0.05
K	0.90	1.00	1.00
L	0.25	0.40	0.30
М	0.10	0.22	0.11
α	0°	8°	-
All Dimensions in mm			

(3) Package Type: X2-DFN1010-6





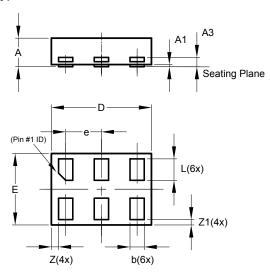
X2-DFN1010-6			
Dim	Min	Max	Тур
Α	-	0.40	0.39
A1	0.00	0.05	0.02
A3			0.13
b	0.14	0.20	0.17
b1	0.05	0.15	0.10
D	0.95	1.05	1.00
Е	0.95	1.05	1.00
е	-		0.35
١	0.35	0.45	0.40
K	0.15		_
Z			0.065
All Dimensions in mm			



Package Outline Dimensions (cont.) (All dimensions in mm.)

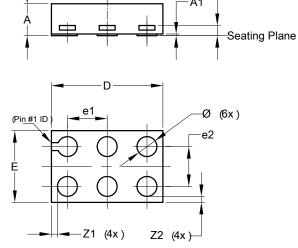
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(4) Package Type X2-DFN1410-6



	X2-DFN1410-6			
Dim	Min	Max	Тур	
Α		0.40	0.39	
A1	0.00	0.05	0.02	
А3	_	_	0.13	
b	0.15	0.25	0.20	
D	1.35	1.45	1.40	
Е	0.95	1.05	1.00	
е	-	-	0.50	
L	0.25	0.35	0.30	
Z			0.10	
Z 1	0.045	0.105	0.075	
All Dimensions in mm				

(5) Package Type: X2-DFN1409-6 Chip Scale Replacement



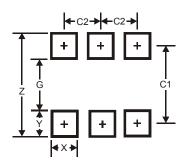
X2-DFN1409-6			
Dim	Min	Max	Тур
Α	-	0.40	0.39
A1	0	0.05	0.02
A3		_	0.13
Ø	0.20	0.30	0.25
D	1.35	1.45	1.40
E	0.85	0.95	0.90
e1		_	0.50
e2		_	0.50
Z 1	_		0.075
Z 2		_	0.075
All Dimensions in mm			



Suggested Pad Layout

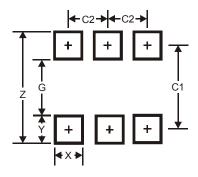
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) Package Type: SOT26



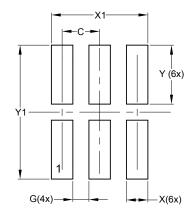
Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Υ	0.80
C1	2.40
C2	0.95

(2) Package Type: SOT363



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

(3) Package Type: X2-DFN1010-6



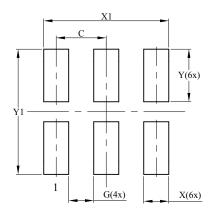
Dimensions	Value (in mm)
С	0.350
G	0.150
Х	0.200
X1	0.900
Y	0.550
Y1	1 250



Suggested Pad Layout (cont.)

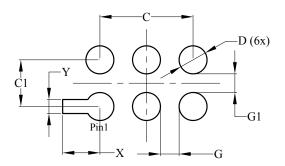
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(4) Package Type X2-DFN1410-6



Dimensions	Value	
Dillielisions	(in mm)	
С	0.500	
G	0.250	
Х	0.250	
X1	1.250	
Y	0.525	
Y1	1.250	

(5) Package Type: X2-DFN1409-6 Chip Scale Replacement



Dimensions	Value (in mm)
С	1.000
C1	0.500
D	0.300
G	0.200
G1	0.200
Х	0.400
Y	0.150



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